

# 1 A low V<sub>F</sub> MEGA Schottky barrier rectifier Rev. 02 — 15 April 2010

Product data sheet

#### 1. **Product profile**

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Average forward current: I<sub>F(AV)</sub> ≤ 1 A
- Reverse voltage: V<sub>R</sub> ≤ 40 V
- Low forward voltage
- High power capability due to clip-bond technology
- AEC-Q101 qualified
- Small and flat lead SMD plastic package

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

### 1.4 Quick reference data

#### Table 1. Quick reference data

 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

$I_{F(AV)} \label{eq:result} \left\{ \begin{array}{c} \text{square wave;} \\ \delta = 0.5; \\ f = 20 \text{ kHz} \end{array} \right. \\ \left. \begin{array}{c} T_{amb} \leq 115 \ ^\circ\text{C} & \begin{tabular}{ll} 1 \\ \hline T_{sp} \leq 140 \ ^\circ\text{C} & \end{tabular} - \end{tabular} 1 \\ \hline V_R & reverse \ voltage & \end{tabular} \\ V_F & forward \ voltage & \end{tabular} I_F = 1 \ A & \end{tabular} \right. \\ \left. \begin{array}{c} \text{square wave;} \\ \delta = 0.5; \\ f = 20 \ \text{kHz} \\ \hline T_{amb} \leq 115 \ ^\circ\text{C} & \begin{tabular}{ll} 1 \\ \hline 1 \\ r_{sp} \leq 140 \ ^\circ\text{C} & \end{tabular} - \end{tabular} 1 \\ 1 \\ A \\ V_R \end{array} \right. \\ \left. \begin{array}{c} \text{square wave;} \\ P \\ $	)	I I					
$ \begin{array}{c c} \delta = 0.5; \\ f = 20 \text{ kHz} \\ \hline T_{amb} \leq 115 \ ^{\circ}\text{C} & \begin{array}{c} 11 \\ - \end{array} & - & 1 & \text{A} \\ \hline T_{sp} \leq 140 \ ^{\circ}\text{C} & - & - & 1 & \text{A} \\ \hline \end{array} \\ \hline V_{\text{F}} & \text{forward voltage} & I_{\text{F}} = 1 \ \text{A} & - & 430 & 490 & \text{m} \\ \end{array} $	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\begin{tabular}{cccccccccccccccccccccccccccccccccccc$	I <sub>F(AV)</sub> average	average forward current	$\delta = 0.5;$				
$V_R$ reverse voltage40V $V_F$ forward voltage $I_F = 1 A$ -430490m			$T_{amb} \le 115 \ ^{\circ}C$	<u>[1]</u> -	-	1	А
$V_F$ forward voltage $I_F = 1 A$ - 430 490 m			$T_{sp} \le 140 \ ^{\circ}C$	-	-	1	А
	V <sub>R</sub>	reverse voltage		-	-	40	V
$V_{\rm p} = 40$ V $-$ 10 50 m	V <sub>F</sub>	forward voltage	$I_F = 1 A$	-	430	490	mV
$r_{\rm R}$ is the second $r_{\rm R}$ + 5 V is the second $\mu$	I <sub>R</sub>	reverse current	$V_R = 40 V$	-	10	50	μA

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.



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### 2. Pinning information

Table 2. Pin	Pinning Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	- /
2	anode	1 2	1 🕂 2
			sym001

[1] The marking bar indicates the cathode.

## 3. Ordering information

Table 3. O	rdering	information		
Type numbe	r	Package		
		Name	Description	Version
PMEG4010E	R	-	plastic surface-mounted package; 2 leads	SOD123W

### 4. Marking

Table 4.	Marking codes	
Type num	ber	Marking code
PMEG401	0ER	BD

### 5. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0, 1	/		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C	-	40	V
I <sub>F(AV)</sub>	average forward current	square wave; $\delta$ = 0.5; f = 20 kHz			
		$T_{amb} \leq 115 \ ^{\circ}C$	[1] -	1	А
		$T_{sp} \le 140 \ ^{\circ}C$	-	1	А
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8 ms	[2] -	50	A
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[3][4]</u> _	0.57	W
			<u>[3][5]</u>	0.95	W
			<u>[3][1]</u>	1.8	W

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#### Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[2]  $T_j = 25 \text{ °C prior to surge.}$ 

[3] Reflow soldering is the only recommended soldering method.

- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

### 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1][2]			
	junction to ambient		[3] _	-	220	K/W
			[4] -	-	130	K/W
			[5] _	-	70	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		<u>[6]</u> _	-	18	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

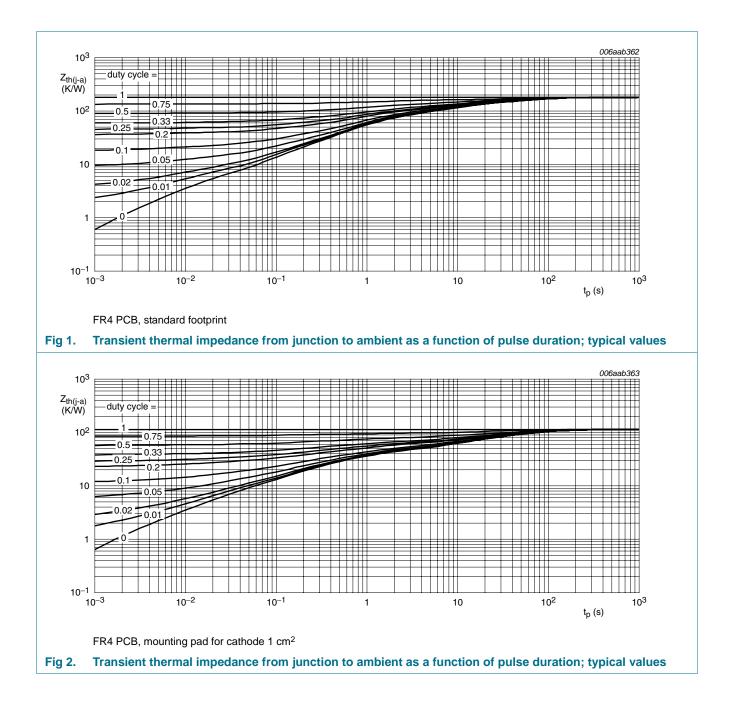
[5] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.

[6] Soldering point of cathode tab.

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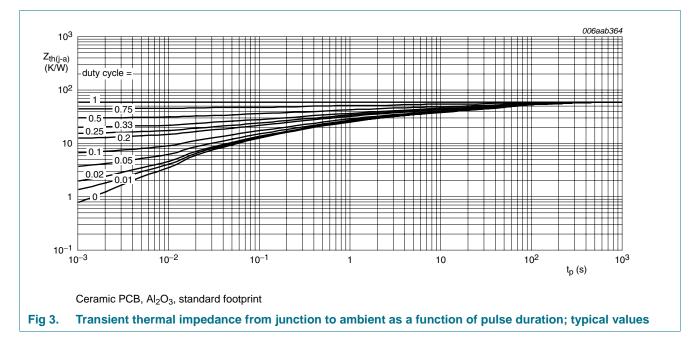
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### 7. Characteristics

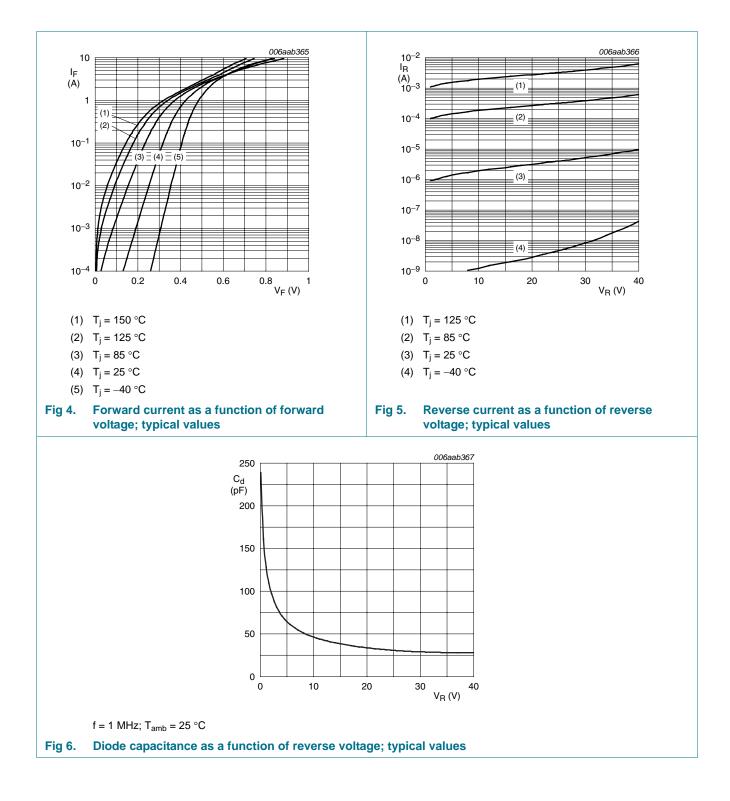
 Table 7.
 Characteristics

$T_j = 25 \ ^{\circ}C$ unless otherwise specified.	
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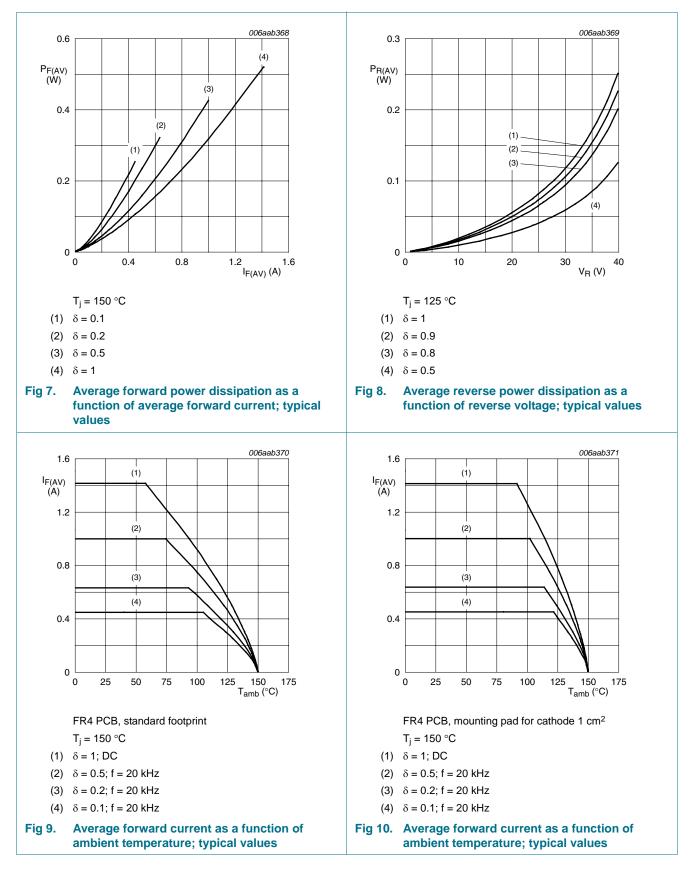
,						
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>F</sub> forward voltage	forward voltage	I <sub>F</sub> = 0.1 A	-	310	360	mV
	I <sub>F</sub> = 1 A	-	430	490	mV	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	3	13	μA
	V <sub>R</sub> = 40 V	-	10	50	μA	
C <sub>d</sub>	diode capacitance	f = 1 MHz				
	$V_R = 1 V$	-	130	-	pF	
		V <sub>R</sub> = 10 V	-	50	-	pF

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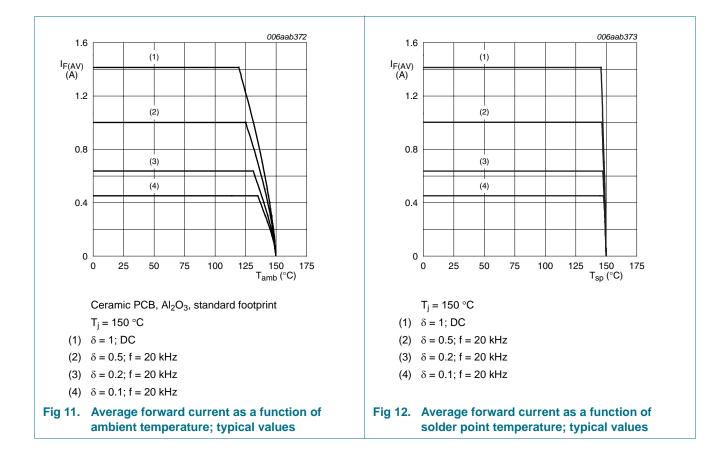
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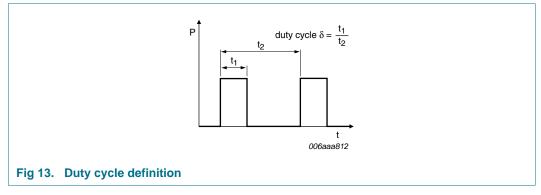
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### 8. Test information

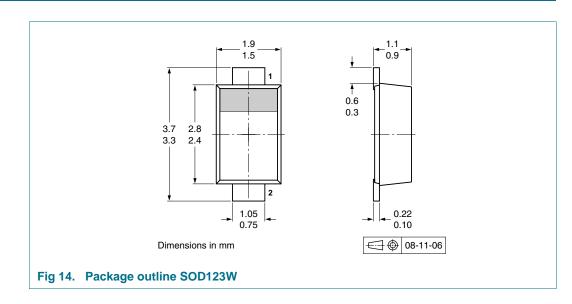


The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,

 $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.



### 9. Package outline

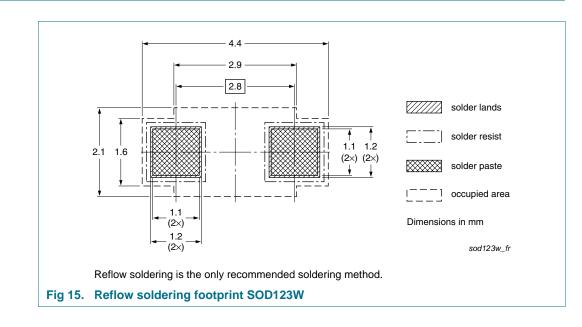
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# **10.** Packing information

	king methods xx are the last i	three digits of the 12NC ordering code.[1]	
Type number	Package	Description	Packing quantity
			3000
PMEG4010ER	SOD123W	4 mm pitch, 8 mm tape and reel	-115
[1] Ear further inf	ormation and the	availability of poolying mathada, and Section 14	

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

## 11. Soldering



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# **12. Revision history**

Table 9.Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4010ER_2	20100415	Product data sheet	-	PMEG4010ER_1
Modifications:	<ul> <li>Table 5 "Lin</li> </ul>	niting values": I <sub>FSM</sub> maximu	um value amended	
	Section 13	<u>'Legal information</u> ": update	ed	
PMEG4010ER_1	20081209	Product data sheet	-	-

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### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

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